A semiconductor chip for forming an electronic image in a digital camera includes an offset canceling column buffer for use with active pixel sensors having a small electrical buffer amplifier within each pixel The active pixel sensors are arranged on a

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includes an source follower current amplifier, which introduces small variations in offset

semiconductor chip with simultaneous access and reset lines. Each active pixel sensor

voltage, causing pattern noise to be introduced into the output signal of the sensed image.

A method and apparatus is disclosed for addressing an array of active pixel sensors in a

sequence coordinated with a column buffer for canceling pattern noise. To cancel pattern

noise, the current row N in the APS cell array is accessed and sampled. Next, the following

row N+1 is accessed thereby resetting the current row. Finally, the previous row N in the

APS cell array is accessed a second time and sampled. Stored samples from the prior row

N are subtracted from the previously sampled signals of the same prior row N to provide

an output pixel signal value for which the APS offset voltage (pattern noise) is cancelled.

In addition, accessing a row of the APS cell array M+1 rows ahead of the current row N

electronically controls image exposure time, which is equal to M times the row scan rate.